NSN 5961-01-564-4533

Unitized Semiconductor Devices - Page 1 of 1



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1 semiconductor device diode

Mounting Method:

Terminal

Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage single semiconductor and 1.0 forward voltage, dc single semiconductor

Current Rating Per Characteristic:

200.00 milliamperes collector current, dc single semiconductor

Power Rating Per Characteristic:

350.0 milliwatts collector power dissipation peak single semiconductor

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Small signal diodes

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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